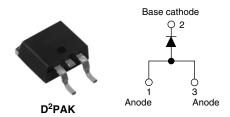




Vishay High Power Products

Input Rectifier Diode, 10 A



PRODUCT SUMMARY						
V _F at 10 A	< 1 V					
I _{FSM}	200 A					
V _{RRM}	800 V/1200 V					

DESCRIPTION/FEATURES

The VS-10ETS..SPbF rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.





FREE

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified for industrial level

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS									
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	12.0	16.0	А						

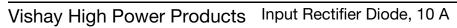
MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	MBOL CHARACTERISTICS VALUES UNIT									
I _{F(AV)}	Sinusoidal waveform	10	А							
V_{RRM}		800/1200	V							
I _{FSM}		200	А							
V _F	10 A, T _J = 25 °C	1.1	V							
TJ		- 40 to 150	°C							

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE	I _{RRM} AT 150 °C
	V	V	mA
VS-10ETS08SPbF	800	900	
VS-10ETS10SPbF	1000	1100	0.5
VS-10ETS12SPbF	1200	1300	

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	VALUES	UNITS							
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180 ° conduction half sine wave	10						
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	170	Α					
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	200						
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	130	- A ² s					
Maximum i-t for fusing		10 ms sine pulse, no voltage reapplied	145						
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1450	A²√s					

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ELECTRICAL SPECIFICATIONS									
PARAMETER	VALUES	UNITS							
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C	1.1	V					
Forward slope resistance	r _t	T 150 °C	20	mΩ					
Threshold voltage	V _{F(TO)}	1) = 150 C	T _J = 150 °C						
Maximum roveres leakage current		T _J = 25 °C	V - Patod V	0.05	mA				
Maximum reverse leakage current	IRM	T _J = 150 °C	V_R = Rated V_{RRM}	0.50					

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W				
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	C/VV				
Soldering temperature	T _S		240	°C				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
			10ET:	S08S				
Marking device		Case style D ² PAK (SMD-220)	10ETS10S					
			10ETS12S					

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



Input Rectifier Diode, 10 A Vishay High Power Products

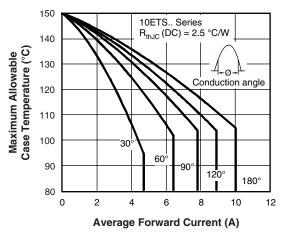


Fig. 1 - Current Rating Characteristics

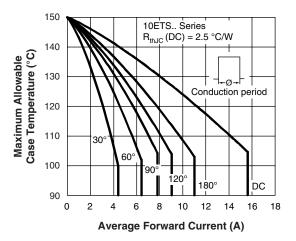


Fig. 2 - Current Rating Characteristics

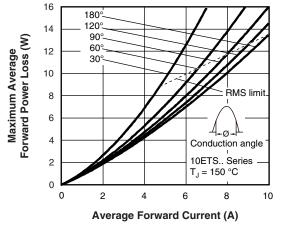


Fig. 3 - Forward Power Loss Characteristics

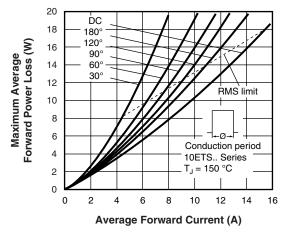


Fig. 4 - Forward Power Loss Characteristics

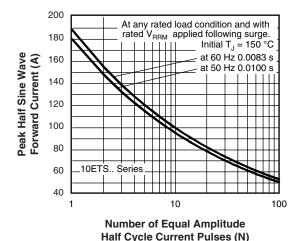


Fig. 5 - Maximum Non-Repetitive Surge Current

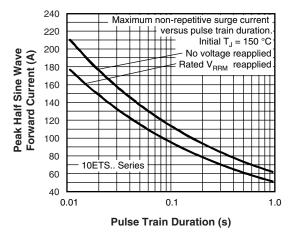


Fig. 6 - Maximum Non-Repetitive Surge Current

VS-10ETS..SPbF High Voltage Series

Vishay High Power Products Input Rectifier Diode, 10 A



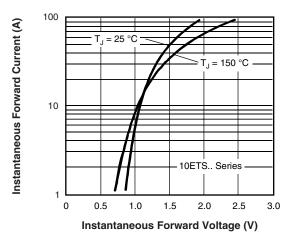


Fig. 7 - Forward Voltage Drop Characteristics

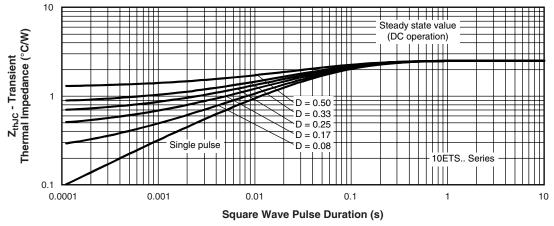


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

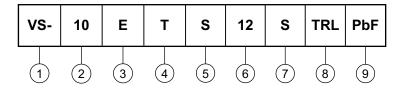


VS-10ETS..SPbF High Voltage Series

Input Rectifier Diode, 10 A Vishay High Power Products

ORDERING INFORMATION TABLE

Device code



- 1 HPP product suffix
- 2 Current rating (10 = 10 A)
- Circuit configuration:

E = Single diode

4 - Package:

T = TO-220AC

5 - Type of silicon:

S = Standard recovery rectifier

08 = 800 V

Voltage code x 100 = V_{RRM}

10 = 1000 V 12 = 1200 V

7 - S = TO-220 D²PAK (SMD-220) version

None = Tube

- TRL = Tape and reel (left oriented)
- TRR = Tape and reel (right oriented)
- 9 PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95046						
Part marking information	www.vishay.com/doc?95054						
Packaging information	www.vishay.com/doc?95032						

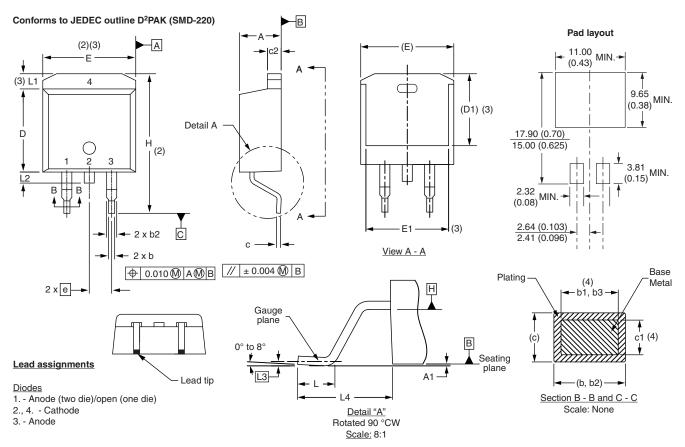
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Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	NOTES		INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3		
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3		
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3		
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC			
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625			
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110			
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3		
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070			
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC			
D	8.51	9.65	0.335	0.380	2	1	L4	4.78	5.28	0.188	0.208			

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB

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